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Complex spectral evolution in a BCS superconductor, ZrB₁₂

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We investigate the electronic structure of a complex conventional superconductor, ZrB_{12} employing high resolution photoemission spectroscopy and *ab initio* band structure calculations. The experimental valence band spectra could be described reasonably well within the local density approximation. Energy bands close to the Fermi level possess t_{2g} symmetry and the Fermi level is found to be in the proximity of quantum fluctuation regime. The spectral lineshape in the high resolution spectra is complex exhibiting signature of a deviation from Fermi liquid behavior. A dip at the Fermi level emerges above the superconducting transition temperature that gradually grows with the decrease in temperature. The spectral simulation of the dip and spectral lineshape based on a phenomenological self energy suggests finite electron pair lifetime and a pseudogap above the superconducting transition temperature.

The relationship between pseudogap phase and superconductivity in high temperature superconductors is an issue of discussion for many years now¹⁻³. While one school believes that the pseudogap arises due to some hidden order and/or effects not associated to superconductivity, the other school attributes pseudogap to the electron pair formation above the transition temperature, T_c as a precursor to the superconducting gap that leads to superconductivity upon establishment of the coherence among the electron pairs at T_c . Independent of these differences, it is realized that electron correlation plays a significant role in the occurrence of pseudogap phase in these unconventional superconductors^{4,5}. Several questions are being asked on whether the pseudogap phase is specific to unconventional superconductors, electron correlation or low dimensionality is a necessity for such phase *etc.*

Apart from these issues, the quest of new superconducting compounds resulted into the discovery of superconductivity in cubic hexane, MB_6 and dodecaborides, MB_{12} (M = Sc. Y, Zr, La, Lu, Th) those attracted much attention due to their interesting electronic properties⁶. ZrB_{12} is one such compound exhibiting relatively high superconducting transition temperature of 6 K in the MB_{12} family⁶. It forms in cubic structure as shown in Fig. 1. In Fig. 1(a), the real lattice positions are shown with the correct bond lengths and atom positions. Although, the structure appears to be complex, it is essentially a rock salt structure constituted by two interpenetrated fcc lattices formed by Zr and B_{12} units as demonstrated in Fig. 1(b) by compressing the B_{12} units for clarity. Various transport and magnetic measurements suggest a Bardeen-Cooper-Schriefer (BCS) type superconductivity in this material, which is termed as conventional superconductivity. Since, Zr atoms are located within the huge octahedral void space formed by the B_{12} units, the superconductivity in these materials could conveniently be explained by the electron-phonon coupling mediated phenomena involving primarily low energy phonon modes associated with the vibration of Zr atoms⁷.

The electronic properties of ZrB_{12} manifest plethora of conflicts involving the mechanism of the transition. For example, there are conflicts on whether it is a type I or type II superconductor⁸, whether it possesses single gap⁹ or multiple gaps¹⁰, *etc.* Interestingly, Gasparov *et al.*¹⁰ found that superfluid density of ZrB_{12} exhibits unconventional temperature dependence with pronounced shoulder at $T/T_c \sim 0.65$. In addition, they find different superconducting gap and transition temperatures for different energy bands, and the values of the order parameter obtained for *p* and *d* bands are 2.81 and 6.44, respectively. Detailed magnetic measurements reveal signature of Meissner, mixed and intermediate states at different temperatures and magnetic fields¹¹. Some of these variances were attributed to surface-bulk differences in the electronic structure¹², the superconductivity at the sample surface¹³⁻¹⁵ *etc.* Evidently, the properties of ZrB_{12} is complex despite exhibiting signatures of BCS type superconductivity. Here, we probed the evolution of the electronic structure of ZrB_{12} employing high resolution photoelectron spectroscopy. The experimental results exhibit spectral evolution anomalous to conventional type superconductor and signature of pseudogap prior to the onset of superconductivity.

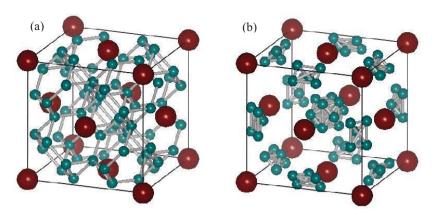


Figure 1 | (a) Crystal structure of ZrB_{12} . (b) B_{12} units are contracted to visualize the isolated B_{12} clusters with better clarity.

Results

Valence band spectra obtained using He II and Al $K\alpha$ excitation energies are shown in Fig. 2(a) exhibiting three distinct features marked by A, B and C beyond 2 eV binding energies. The intensities between 6–10 eV binding energies represented by B are prominent in the He II spectrum, while the relative intensity between 3–4 eV binding energies represented by A is enhanced in the *x*-ray photoemission (XP) spectrum. Such change in intensity in the angle integrated spectra may be attributed to the matrix elements associated to different constituent states forming the eigenstates of the valence band, which is a sensitive function of the photon energy¹⁶. Therefore, the photoemission cross section will vary with the photon energy that can be used to identify the orbital character of the energy bands. Considering this feature of the technique, the spectral feature,

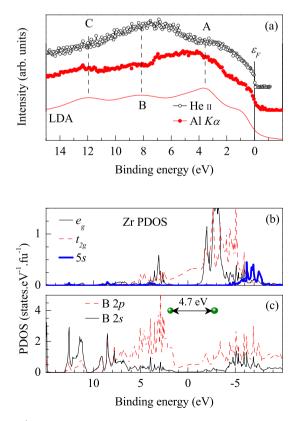


Figure 2 | (a) XP and He II valence band spectra of ZrB₁₂. The lines show the simulated XP spectrum from the band structure results. Calculated partial density of states of (b) Zr 4*d* t_{2g} (dashed line), 4*d* e_g (thin solid line) & 5*s* (thick solid line), and (c) B 2*s* (solid line) and 2*p* (dashed line) partial density of states.

B can be attributed to dominant B 2p orbital character and the feature A to Zr 4d orbital character.

Energy band structure of ZrB₁₂ has been calculated within the local density approximations (LDA). The calculated partial density of states (PDOS) corresponding to Zr 4d & 5s, and B 2s & 2p states are shown in Fig. 2(b) and 2(c), respectively. Zr 5s contribution appears in the energy range of 5-7.5 eV above the Fermi level with negligible contributions in the energy window studied here as shown by thick solid line in Fig. 2(b). B 2s contributions appear beyond 6 eV binding energies. Dominant contribution from B 2p PDOS appears between 1.5 to 10 eV binding energies. The center of mass of the B 2p PDOS (considering both occupied and unoccupied parts) appears around 1.9 eV binding energy. The center of mass of the entire Zr 4d PDOS appear around 2.8 eV above ϵ_F , which is about 4.7 eV above the center of mass of the B 2p PDOS. Thus, an estimate of the charge transfer energy could be about 4.7 eV in this system. The ground state is metallic with flat density of states across ϵ_F arising due to highly dispersive energy bands in this energy range. The density of states at ϵ_F possess close to 2:1 intensity ratio of the B 2p and Zr 4d orbital character.

The electronic states with t_{2g} and e_g symmetries, shown in Fig. 2(b), exhibit almost overlapping center of mass suggesting negligible crystal field splitting (crystal field splitting ~ 100 meV). The energy bands are shown in Fig. 3. e_g bands are relatively narrow and exhibit a gap at ϵ_F . The intensity at ϵ_F essentially have highly dispersive t_{2g} symmetry.

Using the above band structure results, we calculated the XP spectrum considering the photoemission cross section of the constituent partial density of states as discussed later in the Method section. The calculated spectrum shown by solid line in Fig. 2(a) exhibits an excellent representation of the experimental XP spectrum. It is clear that the feature, C in the energy range 10-14 eV corresponds to photoemission signal from B 2*s* levels. The features, A and B arise due to hybridized B 2*p* - Zr 4*d* states. The relative contribution from Zr 4*d* states is higher for the feature A.

In order to probe the electron correlation induced effect on the electronic structure, we have carried out electron density of states calculation using finite electron correlation among the Zr 4*d* electrons, U_{dd} as well as that among B 2*p* electrons, U_{pp} . In Figs. 4(a) and 4(b), we show the calculated results for Zr 4*d* and B 2*p* PDOS with $U_{dd} = 0$ (solid line) and 6 eV (dashed line) for the Zr 4*d* electrons. Even the large value of U_{dd} of 6 eV does not have significant influence on the occupied part of the electronic structure, while an energy shift is observed in the unoccupied part. Such scenario is not unusual considering the large radial extension of 4*d* orbitals and poor occupancy¹⁷. The inclusion of an electron correlation, U_{pp} of upto 4 eV for B 2*p* states exhibits insignificant change in the results. Considering Zr being a heavy element, we carried out similar calculations including spin-orbit interactions and did not find significant modification in



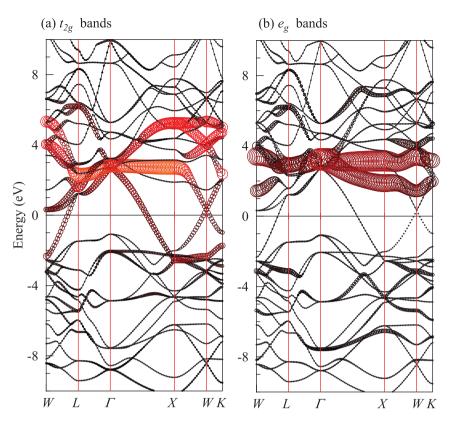


Figure 3 | Energy band dispersions. Symbol size in the left panel show t_{2g} contributions and that on the right panel shows e_g contributions.

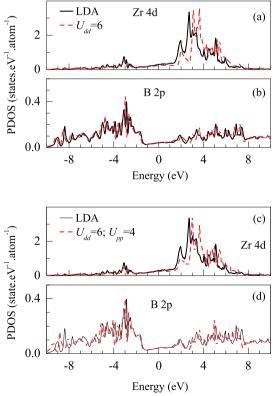


Figure 4 | (a) Zr 4*d* and (b) B 2*p* PDOS obtained from LDA and LDA + *U* calculations ($U_{dd} = 6 \text{ eV}$). (c) Zr 4*d* and (d) B 2*p* PDOS obtained for $U_{dd} = 6 \text{ eV}$ and $U_{pp} = 4 \text{ eV}$.

ant information about the thermodynamic properties of the systems. 4 8 For example, a lineshape dependence of $|\epsilon - \epsilon_F|^2$ corresponds to Formi liquid behavior^{[8,19} abcomes of linesrity of SDOS with

ticle-hole symmetry in this system.

system.

Fermi liquid behavior^{18,19} - absence of linearity of SDOS with $|\epsilon - \epsilon_F|^2$ shown in Fig. 6(a) indicates a deviation from such a behavior in the present case. The decrease in intensity at ϵ_F with the decrease in temperature may arise due to the disorder induced localization of the electronic states. Altshuler & Aronov showed that the charge

the results - we have not shown these later results to maintain clarity in the figure. All these theoretical results suggest that consideration of

electron correlation within the LSDA + U method has insignificant

influence in the occupied part of the electronic structure of this

resolution in Fig. 5. The spectral density of states (SDOS) are calcu-

lated by symmetrizing the experimental spectra; $SDOS = I(\epsilon - \epsilon_F) +$

 $I(\epsilon_F - \epsilon)$ and shown in Figs. 5(c) and 5(d). Such an estimation of SDOS is sensitive to the definition of the Fermi level, which is carefully derived at each temperature by the Fermi cutoff in the valence

band spectra for silver mounted on the sample holder in electrical

connection with the sample and measured using identical experi-

mental conditions. The other effect is the asymmetry across the Fermi level. This can be addressed by obtaining the SDOS by the division of the resolution broadened Fermi-Dirac distribution func-

tion. The results are shown in Figs. 5(e) and 5(f) for He II and He I

spectra, respectively. Clearly, the SDOS obtained following the later

procedure exhibits symmetric SDOS across ϵ_F . The 30 K and 10 K data exhibit large noise above ϵ_F due to the division of negligibly

small intensities by small numbers arising from Fermi-Dirac function at these temperatures. These results demonstrate the reliability

of SDOS extraction procedures and also indicate signature of par-

The spectral lineshape near the Fermi level often provides import-

We now investigate the spectral changes near $_{F}$ with high energy

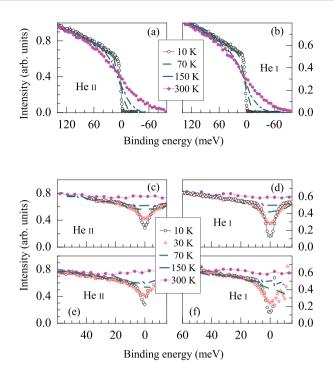


Figure 5 | High resolution spectra near the Fermi level using (a) He II and (b) He I photon energies. The symmetrized spectral density of states (SDOS) for (c) He II and (d) He I spectra, and SDOS obtained by division of resolution broadened Fermi function for (e) He II and (f) for He I spectra.

disorder in a correlated system leads to $|\epsilon - \epsilon_F|^{0.5}$ dependence of the density of states near Fermi level²⁰, which has been proved employing photoemission spectroscopy^{21,22}. In the present case, a plot of SDOS with $|\epsilon - \epsilon_F|^{0.5}$ shown in Fig. 6(b) exhibits deviation from linearity.

Interestingly, the curvatures at the exponents of 0.5 and 2 are opposite indicating an intermediate exponent for the present system. The simulation of SDOS as a function of $|(\epsilon - \epsilon_f)|^{\alpha}$ with $\alpha \approx 0.9$ exhibits linear dependence with energy for all the temperatures studied (see Fig. 6(*c*)). Such a behavior in a conventional superconductor is curious. Most interestingly, in Fig. 6(*c*), all the data below 150 K superimpose exactly and correspond to the same energy scale, while the data at 300 K exhibit similar energy dependence with a different slope. These results suggest signature of an incipient phase transition at an intermediate temperature.

The SDOS at ϵ_F is intense and flat at 300 K with large dispersion of the bands and correspond to a good metallic phase consistent with the band structure results. The decrease in temperature introduces a dip at ϵ_F . The dip gradually becomes more prominent with the decrease in temperature. The same scenario is observed in both, He I and He II spectra indicating this behavior to be independent of the photon energy used. This dip may be attributed to a pseudogap appearing at low temperatures²³. Although the probed lowest temperature is slightly above T_c , the dip grows monotonically with the decrease in temperature - a large suppression of the spectral weight at the Fermi level is observed at 10 K indicating relation of this dip to the superconducting gap. In order to estimate the energy gap in these spectral functions, we used a phenomenological self-energy, $\Sigma_k(\epsilon)$ following the literature²⁴.

$$\Sigma_k(\epsilon) = -i\Gamma_1 + \Delta^2 / [(\epsilon + i\Gamma_0) + \epsilon_k]$$

where Δ represents the gap size. The first term is the energy independent single particle scattering rate and the second term is the BCS self energy. Γ_0 represents the inverse electron pair lifetime. The spectral functions, the imaginary part of the Green's functions, were

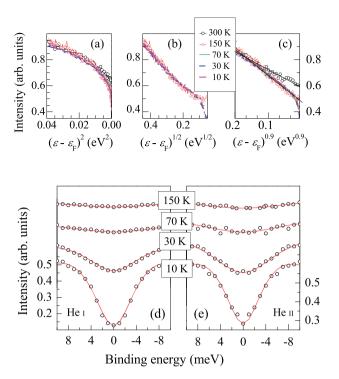


Figure 6 | High resolution spectral density of states is shown as a function of (a) $|\epsilon - \epsilon_F|^2$, (b) $|\epsilon - \epsilon_F|^{1/2}$, and (c) $|\epsilon - \epsilon_F|^{0.9}$. Spectral density of states from (d) He I and (e) He II spectra. The lines represent the spectral functions simulated to fit the experimental spectra.

calculated as follows. $A(\epsilon) = (1/\pi) Im \Sigma_k G_k(\epsilon) = (1/\pi) \Sigma_k \Sigma_k''(\epsilon) / [(\epsilon - \epsilon_k - \Sigma_k'(\epsilon))^2 + (\Sigma_k''(\epsilon))^2]$, where $\Sigma_k'(\epsilon)$ and $\Sigma_k''(\epsilon)$ are the real and imaginary part of the self energy. We find that a finite value of Γ_0 is necessary to achieve reasonable representation of the experimental data. The simulated and experimental spectral density of states are shown by superimposing them in Figs. 6(d) and 6(e) for the He I and He II spectra, respectively. Evidently, the simulated spectra provide a remarkable representation of the experimental spectra.

Discussion

The experimental and calculated band structure results suggest significant hybridization between Zr 4d and B 2p states leading to similar energy distribution of the PDOS. Here, the eigenstates are primarily constituted by the linear combination of the Zr 4d and B 2p states. The antibonding bands possess large Zr 4d orbital character and appear in the unoccupied part of the electronic structure^{25,26}. The energy bands below ϵ_F forming the valence band are the bonding eigenstates consisting of dominant 2p orbital character. The covalency between these states could be attributed to the large radial extension of the 4d orbitals overlapping strongly with the neighboring states as also observed in other 4d systems^{27,28}. The calculated results within the local density approximation are consistent with the experimental spectra - subtle differences between the experiment and theory could not be captured via inclusion of electron correlation and/or consideration of spin-orbit coupling in these LDA calculations.

The band structure results exhibit two important features - (i) the energy bands with t_{2g} symmetry are highly dispersive compared to e_g bands and (ii) the crystal field splitting is negligible. As shown in Fig. 1, the B₁₂ dodecahedrons form an octahedra around Zr sites with the center of mass of the B₁₂ units at the edge centers of the unit cell. The size of the dodecahedrons are quite large with no boron situating on the unit cell edge. Thus, the overlap of B 2*p* orbitals with the t_{2g}

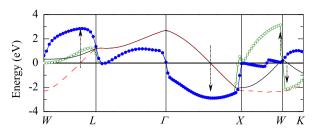


Figure 7 | Energy band dispersions of the t_{2g} bands crossing the Fermi level are shown by lines. The symbols represent the first derivative of the same energy bands. The arrows show the Fermi level crossings.

orbitals is significantly enhanced due to the proximity of borons along the face diagonals, while that with the e_g orbitals is reduced leading to a comparable crystal field potential on both the orbitals. The larger hybridization with the t_{2g} orbitals are also manifested by the large dispersion of the t_{2g} bands spanning across the Fermi level while e_g bands are relatively more localized. From these calculations, the effective valency of Zr was found to vary between (+2.4) to (+2.5) depending on the electron interaction parameters such as correlation strength, spin orbit coupling *etc*.

The Fermi level is located almost at the inflection points of each of the energy band crossing ϵ_F as shown in Fig. 7. This is verified by investigating the first derivative of the energy bands shown by the symbols in the figure. The arrows in the figure indicate Fermi level crossing and corresponding point in the first derivative curves. Evidently, the band crossing correspond to an extremum in the derivative plot. The inflection point is the point, where the curve changes its curvature that corresponds to a change in the character of the conduction electrons (the Fermi surface) from hole-like to electron-like behavior. This behavior is termed as Lifschitz transition²⁹. Thus, this material appear to be lying in the proximity of the Lifschitz transition as also observed in various exotic unconventional superconductors such as Fe-pnictides³⁰. Due to the lack of cleavage plane and hardness of the sample, the Fermi surface mapping of this sample could not be carried out to verify this theoretical prediction experimentally. It is well known that the band structure calculations captures the features in the electronic structure well in the weakly correlated systems as also found in the present case suggesting possibility of such interesting phenomena in this system. We hope, future studies would help to enlighten this issue further.

The high resolution spectra close to the Fermi level indeed exhibit deviation from Fermi liquid behavior - a suggestive of quantum instability in this system as expected from the above results. R. Lortz *et al.*⁷ showed that the resistivity of ZrB_{12} exhibits linear temperature dependence in a large temperature range of 50 K–300 K. The resistivity below 50 K of the normal phase is complex and does not show T^2 -dependence. Both, the resistivity and specific heat data exhibit signature of anharmonic mode of Zr-vibrations. All these observations indicate complexity of the electronic properties, different from a typical Fermi-liquid system consistent with the photoemission results.

A dip appears at the Fermi level at temperatures much higher than the superconducting transition temperature reminiscent of a pseudogap feature. In order to investigate this further, we study the fitting parameters simulating the spectral functions in Fig. 8. The energy gap, Δ is found to be about 7.3 meV and remains almost unchanged in the whole temperature range studied. This gap is significantly larger than the value predicted (1–2 meV) considering BCS behavior. The magnitude of Γ_1 , which is a measure of single particle scattering rate, is quite large and found to decrease with the decrease in temperature. On the other hand, Γ_0 , the inverse pair lifetime is found to be significant and smaller than 2 Δ suggesting proximity to a BCS limit for this system. Γ_0 exhibits temperature dependence quite similar to that of Γ_1 . The decrease in Γ_0 manifests gradual

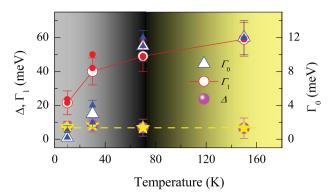


Figure 8 | The gap, Δ , inverse pair lifetime, Γ_0 and single particle scattering rate, Γ_1 as a function of temperature. The open and close symbols correspond to the fitting of He I and He II data, respectively.

enhancement of the electron pair lifetime with the decrease in temperature that eventually leads to the superconducting phase upon attaining coherence among the pairs. Thus, the temperature in the vicinity of 70 K exhibiting the onset of pair formation could be the critical temperature, T^* in this system. The observation of the signature of an energy gap and finite electron pair lifetime above T_c is quite similar to that observed for under-doped cuprates²⁴ and is an indication of precursor effect in this system. Clearly, the electronic structure of this system is complex, appears to be at the crossover of BCS and unconventional behaviors and further studies are required to understand the origin of pseudogap & unusual spectral lineshape.

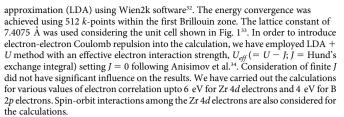
In summary, we studied the electronic structure of ZrB₁₂, predicted to be a complex conventional superconductor employing high resolution photoemission spectroscopy and ab initio band structure calculations. The valence band spectra exhibit multiple features with dominant B 2p orbital character close to the Fermi level. The experimental results could be captured reasonably well within the local density approximations. The electronic states close to Fermi level have $t_{2\sigma}$ symmetry and the filling of the bands is in the proximity of Lifschitz transition. The spectral lineshape near the Fermi level in the high resolution spectra exhibit deviation from typical Fermi liquid behavior. A dip at the Fermi level emerges above the superconducting transition temperature and gradually becomes prominent at lower temperatures. The analysis of the spectral functions within the phenomenological descriptions suggests finite electron pair lifetime above T_c as a signature of a precursor effect to the superconducting transition in this system.

Methods

Sample preparation and characterization. Single crystals of ZrB_{12} were grown by floating zone technique in a Crystal Systems Incorporated (CSI) four-mirror infrared image furnace in flowing high purity Ar gas at a pressure of 2 bar³¹. The quality of the crystal was confirmed and orientation was determined from *x*-ray Laue - diffraction images. The magnetization measurements using a Qunatum Design MPMS magnetometer show a sharp superconducting transition temperature, T_c of 6.1 K¹¹.

Photoemission measurements. The photoemission measurements were performed using a Gammadata Scienta R4000 WAL electron analyzer and monochromatic laboratory photon sources. X-ray photoemission (XP) and ultraviolet photoemission (UP) spectroscopic measurements were carried out using Al $K\alpha$ (14866 eV), He II (40.8 eV) and He I (21.2 eV) photon energies with the energy resolution set to 400 meV, 4 meV and 2 meV, respectively. The melt grown sample was very hard and possesses no cleavage plane. Therefore, the sample surface was cleaned using two independent methods; top-post fracturing and scraping by a small grain diamond file at a vacuum better than 3×10^{-11} torr. Both the procedures results to similar spectra with no trace of impurity related signal in the photoemission measurements. The measurements were carried out in analyzer transmission mode at an acceptance angle of 30° and reproducibility of all the spectra was ensured after each surface cleaning cycle. The temperature variation down to 10 K was achieved by an open cycle He cryostat from Advanced Research systems, USA.

Band structure calculations. The energy band structure of ZrB_{12} was calculated using full potential linearized augmented plane wave method within the local density



To calculate the *x*-ray photoemission spectrum, we have multiplied the partial density of states obtained by the band structure calculations by the corresponding photoemission cross sections for Al $K\alpha$ energy. These cross-section weighted PDOS is convoluted by two Lorentzians with the energy dependent full width at half maxima (FWHM) for the hole & electron lifetime broadenings and a Gaussian with FWHM representing the resolution broadening. The sum of these spectral functions provides the representation of the experimental valence band spectrum.

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Author contributions

S.T. carried out the measurements, band structure calculations, data analysis, and helped in manuscript preparation. D.B. and N.S. carried out photoemission measurements. P.K.B. and G.B. prepared the sample and characterized it. K.M. initiated the study, supervised the measurements, helped in data analysis, prepared the figures & the manuscript.

Additional information

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